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#4115  
T. Young  
5-15-99

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Priority Application Serial No. .... 08/993,663  
Priority Filing Date .... December 18, 1997  
Inventor ..... Salman Akram et al.  
Assignee ..... Micron Technology, Inc.  
Priority Group Art Unit ..... 2812  
Priority Examiner ..... S. Mulpuri  
Attorney's Docket No. .... MI22-1171  
Title: Methods of Forming a Transistor Gate (As Amended)

**PRELIMINARY AMENDMENT**

To: Assistant Commissioner for Patents  
Washington, D.C. 20231

From: James D. Shaurette (Tel. 509-624-4276; Fax 509-838-3424)  
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**AMENDMENTS**

**In the Title**

Please replace the title with --Methods of Forming a Transistor  
Gate--.

**In the Specification**

At p. 1, before the "Technical Field" section, insert